FM IF Amplifier and Demodulator for TV Sound Application

Technology: Bipolar

Features

- Outstanding limiting qualities
- Very few external components
- Wide' supply voltage range
- High ripple rejection

- Minimum IF passage to audio output
- High IF residual carrier rejection
- U 828 B with integrated deemphasis resistor

Case: 8 pin dual inline plastic

Absolute Maximum Ratings

Reference point pin 3

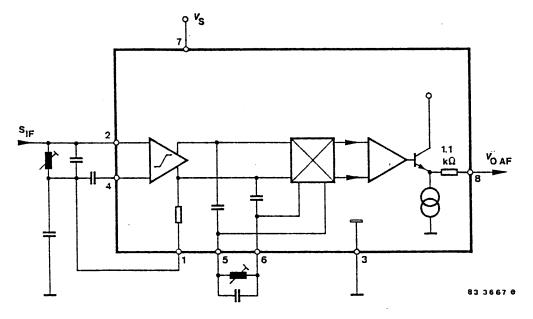
Parameters		Symbol	Value	Unit
Supply voltage	Pin 7	Vs	18	V
Power dissipation	$T_{amb} = 70 \ ^{\circ}C$	P _{tot}	550	mW
Junction temperature		T _i	125	°C
Ambient temperature range		T _{amb}	-15 +70	°C
Storage temperature range		T _{stg}	-25 +125	°C

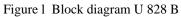
Thermal Resistance

Parameters	Symbol	Maximum	Unit
Junction ambient	R _{thJA}	100	K/W

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U 828 B U 829 B / U 829 BS





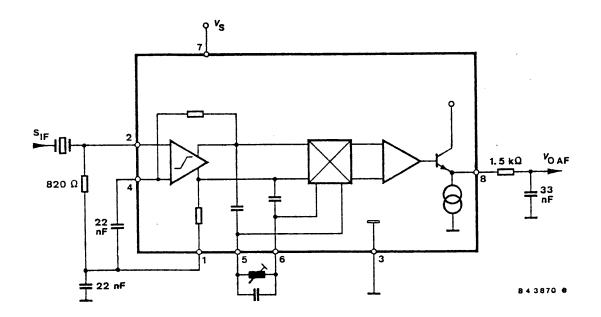


Figure 2 Block diagram U 829 B

Preliminary Information

Electrical Characteristics

 V_S = 12 V, reference point pin 3, T_{amb} = 25 °C, unless otherwise specified

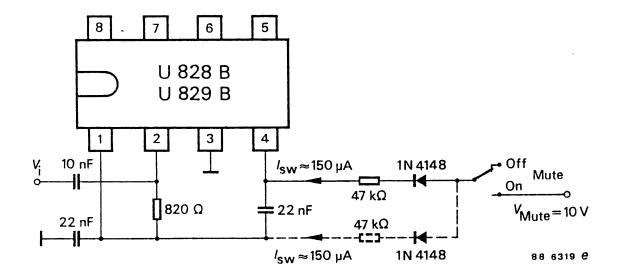
Parameters	Test Conditions / Pin	Symbol	Min	Тур	Max	Unit
Supply voltage range	Pin 7	V _S	10	- 5 P	18	V
Supply current	Pin 7	IS	9.5	14	17.5	mA
Frequency range		f	710		12	MHz
Input voltage for limitation	f = 5.5 MHz,	1			12	INITE
input voltage for initiation	$\Delta f = \pm 50 \text{ kHz},$					
	$f_{mod} = 1 \text{ kHz}, Q^{(1)} = 45$					
	Pin 2	vi		75	90	μV
Input impedance	Pin 2	R _i	15	40		kΩ
		Ci		4.5	6	pF
Output impedance		Ro			200	Ω
AM-rejection	f = 5.5 MHz, $\Delta f = \pm 50 \text{ kHz},$					
	$m = 30 \%, Q^{(1)} = 45,$					
	$V_i = 500 \ \mu V$	k _{AM}	50	60		dB
DC voltage at AF output	$V_i = 0$ Pin 8					
	U 828 B	Vo		5.6		V
	U 829 B	Vo		4.0		V
Ripple rejection	Pin 7,8	k _{hum}		35		dB
IF residual voltage						
without C _D	Pin 8	VoIF		20		mV
AF output voltage	$V_i = 10 \text{ mV}, f = 5.5 \text{ MHz},$ $\Delta f = \pm 50 \text{ kHz},$					
	$f_{mod} = 1 \text{ kHz}, Q^{(1)} = 45$ Pin 8					
	U 828 B	V _{oAF}	0.8		1.3	V
Group 0	= U 829 B	V _{oAF}	1.0		1.90	V
Group 1	= U 829 BS	V _{oAF}	1.0		1.25	V
Group 2	= U 829 BS	V _{oAF}	1.22		1.55	V
Group 3	= U 829 BS	V _{oAF}	1.52		1.90	V
$Q^{(1)} = 20$	U 828 B	V _{oAF}		0.65		V
	U 829 B	V _{oAF}		0.8		V
Distortion	Pin 8					
	$\label{eq:f} \begin{array}{l} f=5.5 \text{ MHz}, \ V_i=10 \text{ mV},\\ FM-Hub=50 \text{ kHz},\\ f_{mod}=1 \text{ kHz} \end{array}$					
$Q^{(1)} = 45$		d		3.0		%
$Q^{(1)} = 20$		d		1.0		%
Signal to noise ratio	$V_i = 10 \text{ mV}$ (unmodulated), according to DIN 45 405		70	80		ID
M. t. C. a.t.	(A-weighted) Pin 8		70	80		dB
Mute function		т			400	
Switching current		I _{sw}	2		400	μΑ
Switching voltage		V _{mute}	3			V

¹⁾ Operation quality factor for the demodulator circuit

TEMIC

U 828 B U 829 B / U 829 BS

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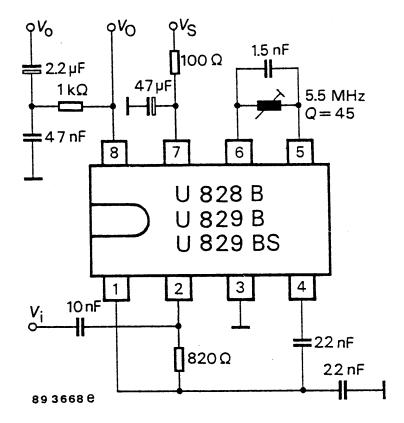
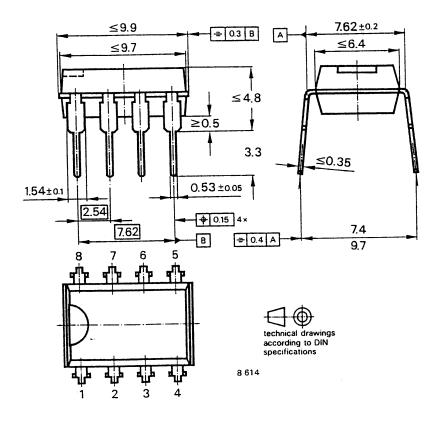


Figure 4 Test circuit

Supply voltage must be disconnected before inserting the integrated circuit in the socket.

Preliminary Information

Dimensions in mm



Case DIP 8-leads

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements and
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

Of particular concern is the control or elimination of releases into the atmosphere of those substances which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) will soon severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of any ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA and
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with and do not contain ozone depleting substances.

We reserve the right to make changes without further notice to improve technical design.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by customer. Should Buyer use TEMIC products for any unintended or unauthorized application, Buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax Number: 49 (0)7131 67 2423

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